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MOSFET - Power, Single P-Channel

-40 V, 23 mΩ, -34.6 A

NVMFS025P04M8L

Features

- NVMFWS025P04M8L Wettable Flanks Product
- Small Footprint for Compact Design 5 x 6 mm
- Low R_{DS(on)} to Minimize Conduction Losses
- Low Capacitance to Minimize Driver Losses
- AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS (T_J = 25° C unless otherwise noted)

| ř. | | | | | |
|---|---------------------|----------------------------|-----------------------------------|----------------|------|
| Parameter | | | Symbol | Value | Unit |
| Drain-to-Source Voltage | | | V _{DSS} | -40 | V |
| Gate-to-Source Voltage | e | | V _{GS} | ±20 | V |
| Continuous Drain | Steady | $T_{C} = 25^{\circ}C$ | ۱ _D | -34.6 | А |
| Current R _{θJC} (Notes 1, 2, 3, 4) | | T _C = 100°C | | -24.5 | |
| Power Dissipation | State | T _C = 25°C | PD | 44.1 | W |
| $R_{\theta JC}$ (Notes 1, 2, 3) | | T _C = 100°C | | 22.1 | |
| Continuous Drain | | $T_A = 25^{\circ}C$ | ۱ _D | -9.4 | А |
| Current R _{θJA} (Notes 1, 3, 4) | Steady | T _A = 100°C | | -6.6 | |
| Power Dissipation | State | T _A = 25°C | PD | 3.5 | W |
| $R_{\theta JA}$ (Notes 1, 3) | | T _A = 100°C | | 1.8 | |
| Pulsed Drain Current | T _A = 25 | °C, t _p = 10 μs | I _{DM} | 204 | А |
| Operating Junction and Storage Temperature Range | | | T _J , T _{stg} | –55 to +175 | °C |
| Source Current (Body Diode) | | | IS | 36.8 | А |
| Single Pulse Drain-to-Source Avalanche Energy (I _{L(pk)} = TBD A) | | | E _{AS} | 152 | mJ |
| Lead Temperature for Soldering Purposes (1/8" from case for 10 s) | | | ΤL | 260 | °C |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL RESISTANCE MAXIMUM RATINGS (Note 1)

| Parameter | Symbol | Value | Unit |
|---|-----------------|-------|------|
| Junction-to-Case - Steady State (Note 3) | $R_{\theta JC}$ | 3.4 | °C/W |
| Junction-to-Ambient - Steady State (Note 3) | $R_{\theta JA}$ | 42.4 | |

1. The entire application environment impacts the thermal resistance values shown, they are not constants and are only valid for the particular conditions noted.

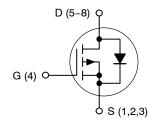
 Psi (Ψ) is used as required per JESD51–12 for packages in which substantially less than 100% of the heat flows to single case surface.

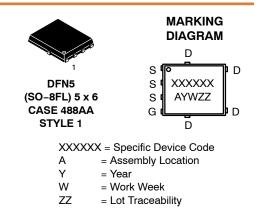
3. Surface-mounted on FR4 board using a 650 mm^2 , 2 oz. Cu pad.

 Continuous DC current rating. Maximum current for pulses as long as 1 second is higher but is dependent on pulse duration and duty cycle.

| V _{(BR)DSS} | R _{DS(on)} MAX | I _D MAX |
|----------------------|-------------------------|--------------------|
| -40 V | 23 mΩ @ −10 V | -34.6 A |
| -40 V | 37 mΩ @ –4.5 V | -34.0 A |







ORDERING INFORMATION

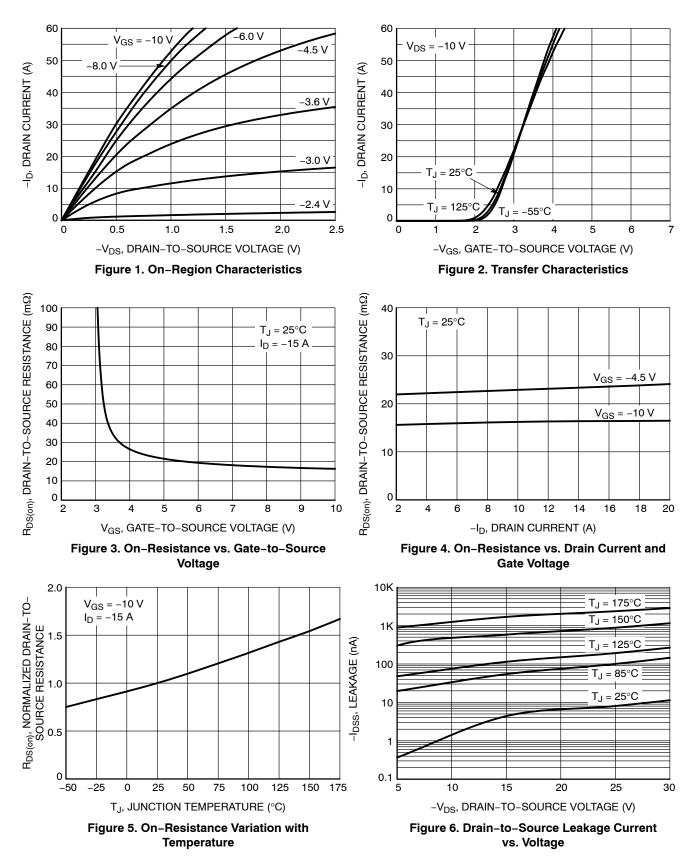
See detailed ordering, marking and shipping information in the package dimensions section on page 5 of this data sheet.

ELECTRICAL CHARACTERISTICS (T_J = 25° C unless otherwise noted)

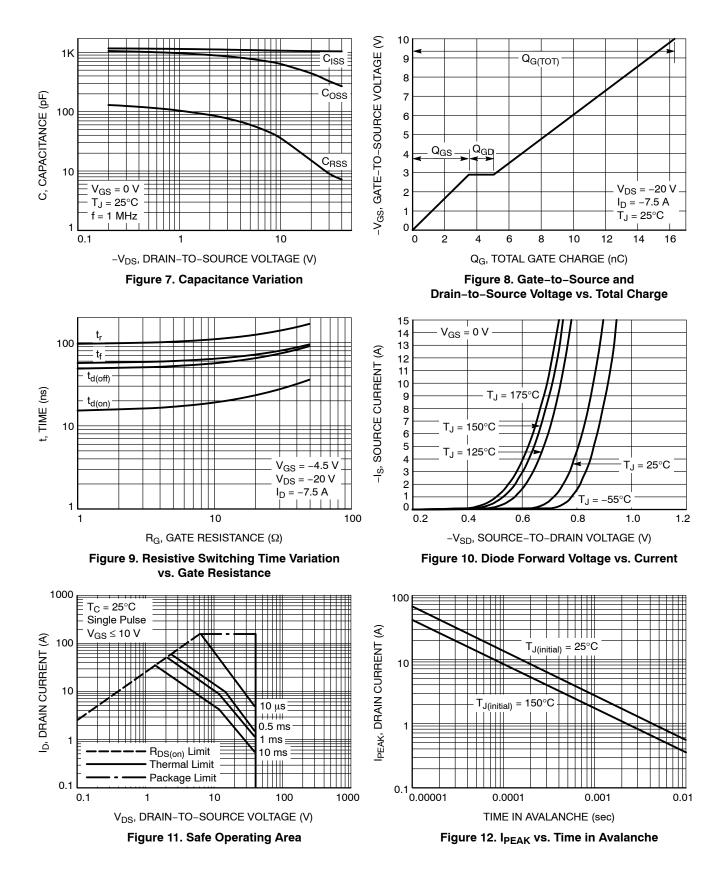
| Symbol | Test Condition | | Min | Тур | Max | Unit |
|--|---|--|---|--|---|---|
| • | | | | | | |
| V _{(BR)DSS} | V _{GS} = 0 V, I _D = -250 μA | | -40 | | | V |
| V _{(BR)DSS} / T _J | | | | 20.40 | | mV/° C |
| I _{DSS} | V _{GS} = 0 V, V _{DS} = -40 V | T _J = 25°C T ₁ = 125°C | | | -1 -100 | μΑ |
| IGSS | .5 .=0 0 | | | | ±100 | nA |
| 400 | | 0 | | | | |
| V _{GS(TH)} | V _{GS} = V _{DS} , I _D | = –255 μA | -1.0 | | -2.4 | V |
| V _{GS(TH)} / TJ | (G2 - (D2, ID - 200 far) | | | 4.94 | | mV/° C |
| R _{DS(on)} | V _{GS} = -10 V, I _D = -15 A | | | 16.6 | 23 | mΩ |
| · · / | V _{GS} = -4.5 V, | _D = -7.5 A | | 23.6 | 37 | |
| 9 _{FS} | V _{DS} = -1.5 V, I _D = -15 A | | | 30.8 | | S |
| - | | | | | | 1 |
| C _{iss} | V _{GS} = 0 V, f = 1.0 MHz, V _{DS} = -20 V | | | 1058 | | pF |
| C _{oss} | | | | 446 | | |
| C _{rss} | | | | 19 | | |
| V _{GP} | V _{GS} = -4.5 V, V _{DS} = -20 V, I _D = -7.5 A | | | 2.9 | | V |
| Q _{G(TOT)} | | | | 7.56 | | nC |
| Q _{G(TH)} | | | | 1.93 | | nC |
| Q _{GS} | | | | 3.4 | | 1 |
| Q _{GD} | | | | 1.55 | | |
| Q _{G(TOT)} | V_{GS} = -10 V, V_{DS} = -20 V, I _D = -7.5 A | | | 16.3 | | nC |
| lote 6) | | | | | | |
| t _{d(on)} | | | | 16 | | ns |
| tr | V _{GS} = -4.5 V, V | -20 V, | | 99 | | 1 |
| t _{d(off)} | $I_{\rm D} = -7.5 \text{A}, R_{\rm G} = 2.5 \Omega$ | | | 50 | | |
| t _f | | | | 58 | | |
| RISTICS | | | | | | |
| V _{SD} | V _{GS} = 0 V, I _S = -15 A | $T_J = 25^{\circ}C$ | | -0.86 | -1.20 | V |
| + | | 1j = 120 U | | | | |
| _ | V _{GS} = 0 V, dI _S /dt = 100 A/μs, I _S = −15 A | | | | | ns |
| | | | | | | |
| ۴b | | | | ð | | |
| | V(BR)DSS V(BR)DSS/ TJ IDSS IDSS IGSS VGS(TH) VGS(TH)/ TJ RDS(on) 9FS Ciss Coss Crss VGG(TH) QG(TOT) QGC(TOT) QGC(TOT) QGC(TOT) QGC(TOT) QGC(TOT) Index VGS(TH) T VGS(TH)/ T GO(TOT) QGC(TOT) QGC(TOT) QGC(TOT) QGC(TOT) Index T | $\begin{tabular}{ c c c c c } \hline V_{(BR)DSS} & V_{GS} = 0 \ V, \ I_D = 0 \ V, \ V_{DS} = -40 \ V \ V_{DS} = -4.5 \ V \ V_{DS} = -7.5 \ A \ A \ A \ A \ A \ A \ A \ A \ A \ $ | $\begin{tabular}{ c c c c c } \hline V_{(BR)DSS} & V_{GS} = 0 \ V, \ I_D = -250 \ \mu A \\ \hline V_{(BR)DSS} & V_{GS} = 0 \ V, \ V_{DS} = -40 \ V \\ \hline T_J = 125^\circ C \\ \hline$ | $\begin{array}{c c c c c c c c c c c c c c c c c c c $ | $ \begin{array}{ c c c c c } \hline V_{(BR)DSS} & V_{GS} = 0 \ V, \ I_D = -250 \ \mu A & -40 & \\ \hline V_{(BR)DSS} & & & \\ \hline V_{DS} = -40 \ V & & \\ \hline I_DSS & V_{DS} = -40 \ V & \\ \hline V_{DS} = -40 \ V & \\ \hline T_J = 25^\circ C & \\ \hline T_J = 125^\circ C & \\ \hline T_J =$ | $ \begin{array}{c c c c c c c c c c c c c c c c c c c $ |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 5. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%. 6. Switching characteristics are independent of operating junction temperatures.

TYPICAL CHARACTERISTICS



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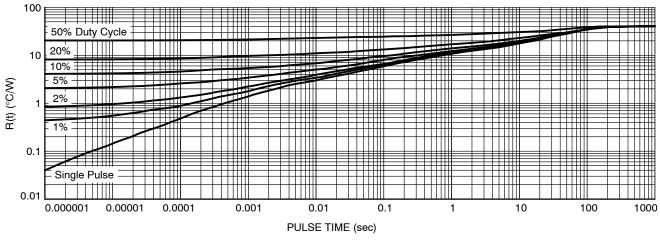


Figure 13. Thermal Characteristics

DEVICE ORDERING INFORMATION

| Device | Marking | Package | Shipping [†] |
|--------------------|---------|-----------|-----------------------|
| NVMFS025P04M8LT1G | 025P04 | SO8FL | 1500 / Tape & Reel |
| NVMFWS025P04M8LT1G | 025P4W | (Pb-Free) | |

+ For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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